

## AMENDMENTS

### In The Claims:

This listing of claims replaces all prior versions, and listings, of claims in the application.

1. (Currently Amended) A semiconductor laser device comprising:  
a stem body having a reference surface; a heat radiation block which is provided on the reference surface of the stem body and which has a semiconductor laser chip mounted on a side face thereof; and a lead which extends through the stem body, wherein  
a portion of the lead protruding on a reference surface side is placed on one side surface side of the heat radiation block on which the semiconductor laser chip is mounted, and  
the semiconductor laser device further comprises a cover which is attached to the side face of the heat radiation block at both ends thereof so as to surround the semiconductor laser chip and the portion of the lead protruding on the reference-surface side, in conjunction with the side face of the heat radiation block, and which is opened on at least one side of the cover that is a beam-output side of the semiconductor laser chip, wherein the cover is only a semi-cylinder which does not extend beyond the heat radiation block.
2. (Original) The semiconductor laser device according to Claim 1, wherein  
the cover is made of a resin material.
3. (Original) The semiconductor laser device according to Claim 1, wherein  
a depth of the cover in the beam-output direction of the semiconductor laser chip is substantially equal to a depth of the heat radiation block.
4. (Original) The semiconductor laser device according to Claim 1, wherein  
the cover has a recessed portion for putting therein a resin for bonding the cover to the heat radiation block.
5. (Original) The semiconductor laser device according to Claim 1, wherein  
the heat radiation block has a recessed portion for putting therein a resin for bonding the cover to the heat radiation block.